

# **SPB35N10 G**

#### SPB35N10 G Information

| www.hersener.com   | Part Number  | SPB35N10 G  |     |
|--------------------|--------------|---|-----|
|                    | Manufacturer | Infineon Technologies   |     |
|                    | Category     | Discrete Semiconductor Products<br>Transistors - FETs, MOSFETs - Single |     |
|                    | Description  | MOSFET N-CH 100V 35A D2PAK  | 5.4 |
|                    | Package      | TO-263-3, D2Pak (2 Leads + Tab), TO-263AB                               |     |
|                    |              | For the pricing/inventory/lead time, please contact us                  |     |
| For Reference Only |              | Website: https://www.heisener.com<br>E-mail: salesdept@heisener.com     | Re  |



Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## SPB35N10 G Specifications

| Manufacturer Part Number               | SPB35N10 G                                |            |
|--|---|------------|
| Manufacturer                           | Infineon Technologies                     |            |
| Category                               | Discrete Semiconductor Products           |            |
|  | Transistors - FETs, MOSFETs - Single      |            |
| Package                                | TO-263-3, D2Pak (2 Leads + Tab), TO-263AB |            |
| Series                                 | SIPMOS?                                   |            |
| FET Type                               | N-Channel                                 |            |
| Technology                             | MOSFET (Metal Oxide)                      |            |
| Drain to Source Voltage (Vdss)         | 100V                                      |            |
| Current - Continuous Drain (Id) @ 25°C | 35A (Tc)                                  |            |
| Drive Voltage (Max Rds On, Min Rds On) | 10V                                       |            |
| Vgs(th) (Max) @ Id                     | 4V @ 83µA                                 |            |
| Gate Charge (Qg) (Max) @ Vgs           | 65nC @ 10V                                |            |
| Input Capacitance (Ciss) (Max) @ Vds   | 1570pF @ 25V                              |            |
| Vgs (Max)                              | $\pm 20\mathrm{V}$                        |            |
| FET Feature                            | -   |            |
| Power Dissipation (Max)                | 150W (Tc)                                 |            |
| Rds On (Max) @ Id, Vgs                 | 44 mOhm @ 26.4A, 10V                      |            |
| Operating Temperature                  | -55°C ~ 175°C (TJ)                        |            |
| Mounting Type                          | Surface Mount                             |            |
| Supplier Device Package                | PG-TO263-3-2                              |            |
| Package / Case                         | TO-263-3, D2Pak (2 Leads + Tab), TO-263AB |            |
|  | Repo                                      | rt errors? |

#### SPB35N10 G Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

### SPB35N10 G Payment Methods





If you have any question about SPB35N10 G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com